
ROITHNER LASERTECHNIK PRESENTS...

HIGH POWER RED LASER DIODES



5.6 mm, single mode, with monitor photodiode

QL63K4SA-L, **635 nm**, 60 mW, sm, 40 °C, 5.6 mm

QL65L6SA, **650 nm**, 80 mW, sm, 60 °C, 5.6 mm



TO3 or C-mount, multi mode

RLT635-150-C, 635 nm, 150 mW, mm, C-mount

RLT635-150-TO3, 635 nm, 150 mW, mm, TO3

RLT635-300-TO3, 635 nm, 300 mW, mm, TO3

RLT67300T, 670 nm, 300 mW, mm, TO3

HIGH POWER UV LED



NS375M-CPFV, 375 nm, 110-130 mW at 180 mA, 27 chips, 14.5x14.5 mm² SMD ceramic

PHOTODIODE WITH INTEGRATED AMPLIFIER



silicon photodiode with ultra low noise JFET transimpedance amplifier, integrated feedback resistor and capacitor, hermetical TO5 package with collimating glass lens, very low offset and drift parameters, dual supply voltage +/-5V up to +/-18V, operating temp.: -25° .. +85°C, RoHS and WEEE conformity

IQ800L, active area 4.8mm², transimpedance 100 MOhm, 35 us, 10 kHz, +/- 50 degree

IQ801L, active area 4.8mm², transimpedance 10 MOhm, 15 us, 25 kHz, +/- 50 degree

IQ802L, active area 4.8mm², transimpedance 1 MOhm, 3 us, 120 kHz, +/- 50 degree

[datasheet](#)



pricelist, 1M, updated 10 July, 2007

[download pricelist](#)



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Best regards,

Andreas Roithner

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